

IFW/2815



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Ricky Amos

Group Art Unit: 2815

Serial No.: 09/995,031

Examiner: Matthew Landau

Filed: Nov. 29, 2001

In Response to Office Action
Dated: Oct. 12, 2004

For: High Temperature Processing Compatible Metal Gate
Electrode For FETs and Method for Fabrication

Attorney Docket No.: YOR920010633US1 (062)

Certificate of Mailing

I hereby certify that this paper (along with any referred to as being attached or enclosed) is being deposited with the United States Postal Service on the date shown below with sufficient postage as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

Date: 1/12, 2005

R. TUNG

RESPONSE TO OFFICE ACTION

Commissioner for Patents
Alexandria, VA 22313-1450

Dear Sir:

In response to an Office Action mailed Oct. 12, 2004,
please enter the following amendments and consider the following
remarks.